

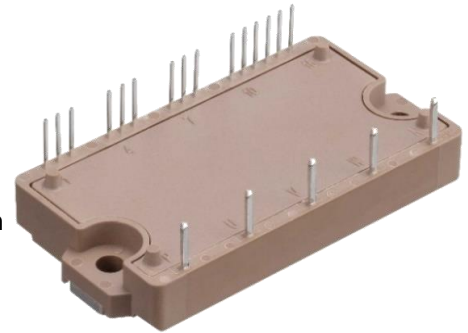
6MBP20XRHA065-50

IGBT Modules

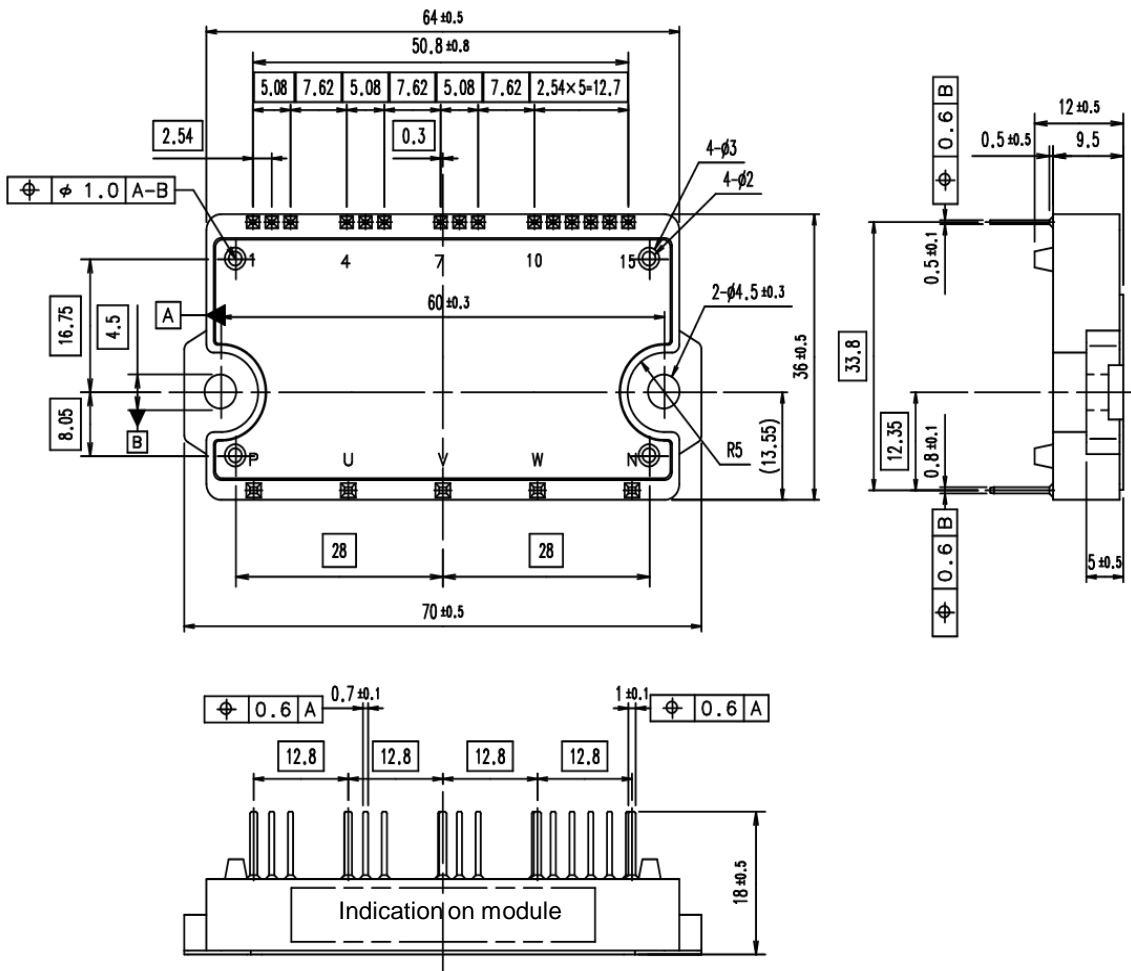
IGBT Module (X series)
650V / 20A / IPM

■ **Features**

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



■ **Outline drawing (Unit : mm)**



Weight:55g(typ.)

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Absolute maximum ratings

$T_C=25^\circ\text{C}$, $T_{vj}=25^\circ\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Items		Symbol	Conditions	Min.	Max.	Units
Collector-emitter voltage		V_{CES}	*1	-	650	V
Short circuit voltage		V_{SC}	*2	200	400	V
Inverter	Collector current	I_C	DC	-	20	A
		I_{CP}	1ms	-	40	A
		$-I_C$	Duty=100% *3	-	20	A
Total power dissipation		P_{tot}	IGBT 1 device *4	-	123	W
Brake	Collector current	I_C	DC	-	-	A
		I_{CP}	1ms	-	-	A
	Forward current of diode	I_F		-	-	A
Total power dissipation		P_{tot}	IGBT 1 device *4	-	-	W
Supply voltage of pre-driver		V_{CC}	*5	-0.5	20	V
Input signal voltage		V_{in}	*6	-0.5	$V_{CC}+0.5$	V
Alarm signal voltage		V_{ALM}	*7	-0.5	V_{CC}	V
Alarm signal current		I_{ALM}	*8	-	20	mA
Virtual junction temperature		T_{vj}		-	175	$^\circ\text{C}$
Operating virtual junction temperature		T_{vjop}		-	150	$^\circ\text{C}$
Operating case temperature		T_C		-20	125	$^\circ\text{C}$
Storage temperature		T_{stg}		-40	125	$^\circ\text{C}$
Solder temperature		T_{sol}	*9	-	260	$^\circ\text{C}$
Isolating voltage		V_{isol}	*10	-	2500	Vrms
Mounting torque of screws to heat sink		M_s	Mounting(M4)	-	1.7	Nm
Mounting torque of screws to terminals		M_t	Main terminals(M4)	-	-	Nm

Notes

- *1: V_{CES} shall be applied to the input voltage between terminal P-(U,V, W) and (U,V, W)-N.
- *2: In the case of the load inductance to be over 1 μH .
- *3: Duty=150 $^\circ\text{C}/R_{th(i-c)}/(I_F \times V_F \text{ Max.}) \times 100$
- *4: $P_{tot}=150^\circ\text{C}/R_{th(i-c)}$
- *5: V_{CC} shall be applied to the input voltage between terminal No.3 and 1, 6 and 4, 9 and 7,11 and 10.
- *6: V_{in} shall be applied to the input voltage between terminal No.2 and 1, 5 and 4, 8 and 7,12~14 and 10.
- *7: V_{ALM} shall be applied to the voltage between terminal No.15 and 10.
- *8: I_{ALM} shall be applied to the input current to terminal No.15.
- *9: Immersion time 10 \pm 1sec. 1time
- *10: Terminal to base, 50/60Hz sine wave 1min. All terminals should be connected together during the test.

Electrical characteristics

Main circuit

$T_{vj}=25^\circ\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item		Symbol	Conditions	Min.	Typ.	Max.	Units	
Inverter	Collector current at off signal Input	I_{CES}	$V_{CE} = 650\text{V}$	-	-	1.0	mA	
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 20\text{A}$	Terminal	-	-	1.70	V
				Chip	-	1.40	-	V
Forward voltage of FWD	V_F	$I_F = 20\text{A}$	Terminal	-	-	1.90	V	
			Chip	-	1.60	-	V	
Brake	Collector current at off signal Input	I_{CES}	$V_{CE} = -\text{V}$	-	-	-	mA	
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -\text{A}$	Terminal	-	-	-	V
				Chip	-	-	-	V
Forward voltage of FWD	V_F	$I_F = -\text{A}$	Terminal	-	-	-	V	
			Chip	-	-	-	V	
Switching time *11	t_{on}	$I_C = 20\text{A}$	$T_{vj}=150^\circ\text{C}$	$V_{DC} = 300\text{V}$	0.5	-	-	μs
					0.5	-	-	μs
	t_{off}	$I_C = 20\text{A}$	$T_{vj}=150^\circ\text{C}$	$V_{DC} = 300\text{V}$	-	-	2.0	μs
					-	-	1.7	μs
	t_{rr}	$I_F = 20\text{A}$	$T_{vj}=150^\circ\text{C}$	-	-	0.5	μs	

*11: Turn on time ($t_{on} = t_{d(on)} + t_r$), Turn off time ($t_{off} = t_{d(off)} + t_f$)

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● Control circuit

$T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units	
Supply current of P-side pre-driver (per one unit)	I_{ocp}	Switching frequency (f_{sw}) = 0~15kHz $T_c = -20\sim 125^{\circ}\text{C}$	-	-	8	mA	
Supply current of N-side pre-driver	I_{ocn}		-	-	21	mA	
Input signal threshold voltage	$V_{inth(on)}$	$V_{in}\text{-GND}$	ON	1.2	1.4	1.6	V
	$V_{inth(off)}$		OFF	1.5	1.7	1.9	V

● Protection circuit

$T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units	
Over current protection level	I_{oc}	$T_{vj}=150^{\circ}\text{C}$	Inverter	30	-	-	A
			Brake	-	-	-	A
Over current protection delay time	t_{dOC}	$T_{vj}=150^{\circ}\text{C}$	-	4.0	-	μs	
Short circuit protection delay time	t_{dSC}	$T_{vj}=150^{\circ}\text{C}$	-	2.0	-	μs	
IGBT chips over heating protection temperature level	T_{jOH}	Surface of IGBT Chips	175	-	-	$^{\circ}\text{C}$	
Over heating protection hysteresis	T_{jH}		-	20	-	$^{\circ}\text{C}$	
Under voltage protection level	V_{UV}		11.0	-	12.5	V	
Under voltage protection hysteresis	V_H		0.2	0.5	-	V	
Alarm signal hold time	$t_{ALM(OC)}$	ALM-GND	1.0	2.0	2.4	ms	
	$t_{ALM(UV)}$	$T_c=-20\sim 125^{\circ}\text{C}$	$V_{CC}\geq 10\text{V}$	3.5	4.0	4.5	ms
	$t_{ALM(TjOH)}$			7.0	8.0	9.0	ms
Alarm signal voltage	V_{ALMH}	ALM-GND, without protection	14.5	-	15.0	V	
Resistance for current limit	R_{ALM}		960	-	1570	Ω	

■ Thermal resistance characteristics ($T_c = 25^{\circ}\text{C}$)

Item	Symbol	Min.	Typ.	Max.	Units		
Thermal resistance junction to case *12	RC-IGBT	$R_{th(j-c)}$	-	-	1.21		
						K/W	
	Brake	IGBT	$R_{th(j-c)Q}$	-	-	-	K/W
		FWD	$R_{th(j-c)D}$	-	-	-	K/W
Thermal resistance case to heat sink *13	$R_{th(c-s)}$	-	0.05	-	K/W		

*12: For 1 device, the measurement point of the case is just under the chip.

*13: This is the value which is defined mounting on the additional heat sink with 1 W/(m·K) thermal grease.

■ Noise immunity ($V_{DC}=300\text{V}$, $V_{CC}=15\text{V}$)

Item	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width 1 μs , polarity \pm , 10min. Judge: no over-current, no miss operating	± 2.0	-	-	kV

■ Recommended operating conditions

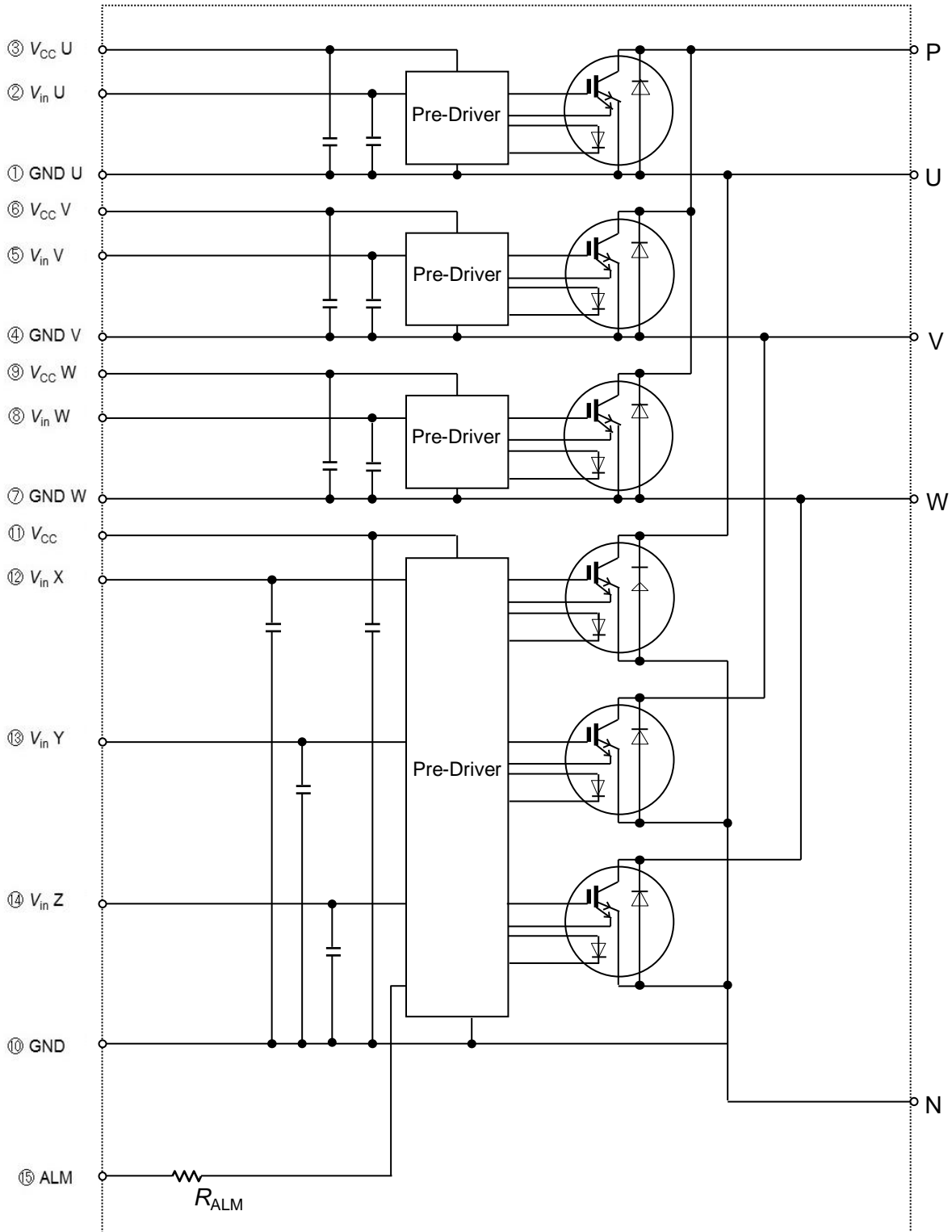
Item	Symbol	Min.	Typ.	Max.	Units
DC bus voltage	V_{DC}	-	-	400	V
Power supply voltage of pre-driver	V_{CC}	13.5	15.0	16.5	V
Switching frequency of IPM	f_{sw}	-	-	20.0	kHz
Arm shoot through blocking time for IPM's input signal *14	t_{dead}	1.5	-	-	μs
Screw torque (M4)	-	1.3	-	1.7	Nm

*14: $t_{dead} = t_{off} - t_{d(on)}$

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■ Block diagram



- Pre-drivers include following functions
1. Amplifier for driver
 2. Short circuit protection
 3. Under voltage lockout circuit
 4. Over current protection
 5. IGBT chip over heating protection

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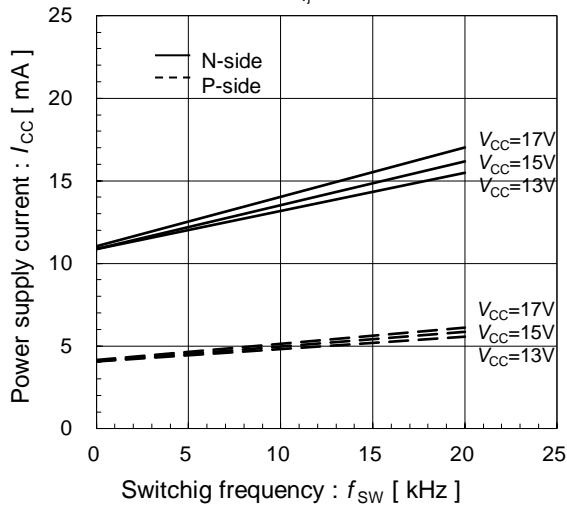
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■ Characteristics (representative)

● Control circuit

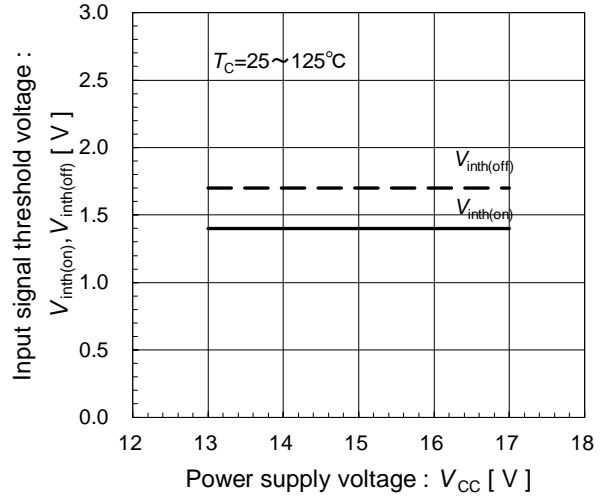
Power supply current vs. switching frequency (typ.)

$T_{vj} = 25^\circ\text{C}$

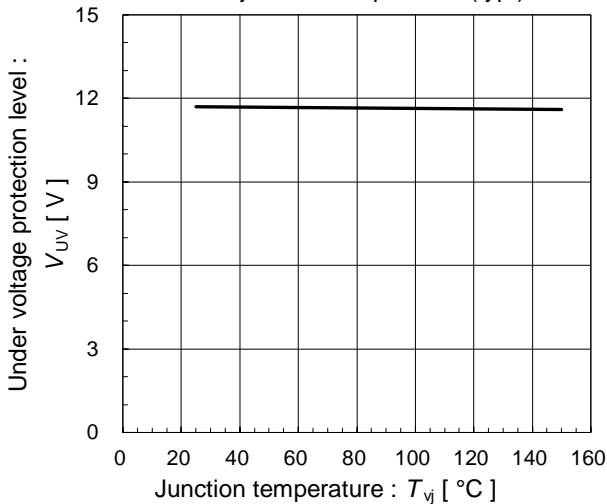


Input signal threshold voltage vs. power supply voltage (typ.)

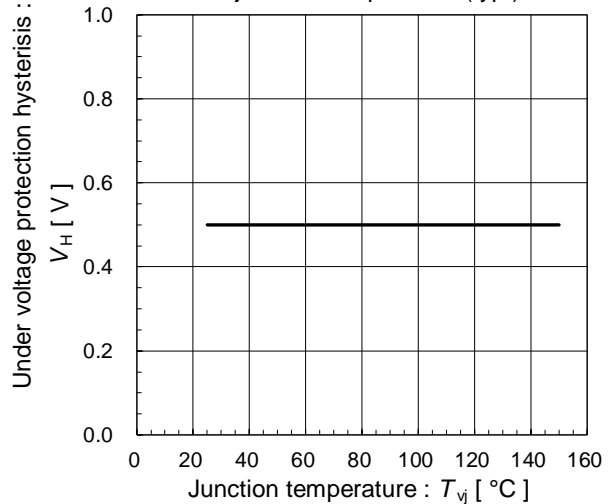
$T_c = 25 \sim 125^\circ\text{C}$



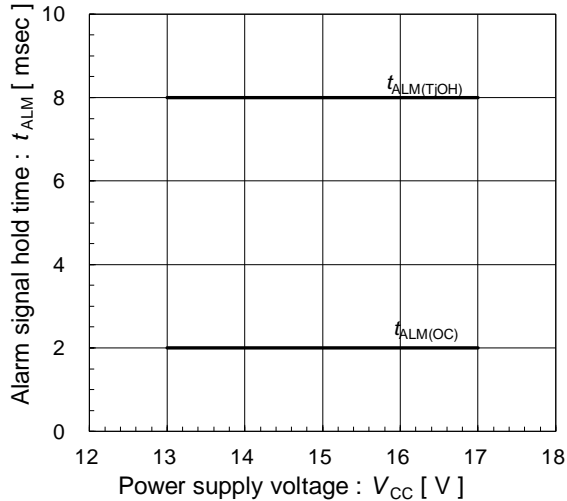
Under voltage protection level vs. junction temperature (typ.)



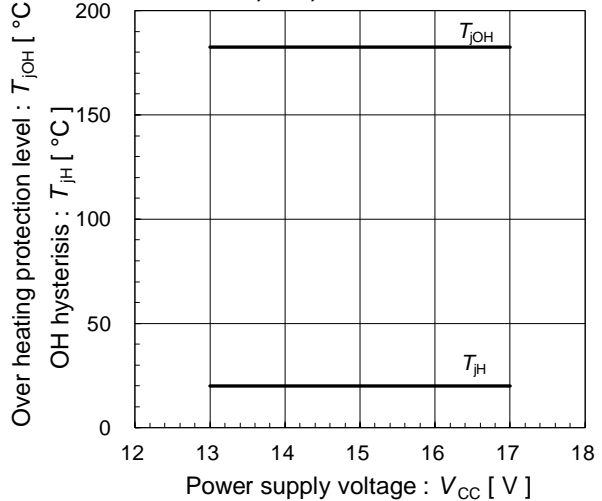
Under voltage protection hysteresis vs. junction temperature (typ.)



Alarm signal hold time vs. power supply voltage (typ.)



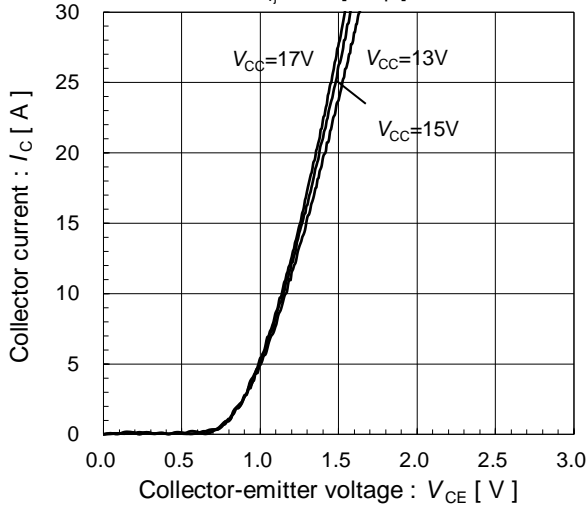
Over heating characteristics T_{jOH}, T_{jH} vs. V_{CC} (typ.)



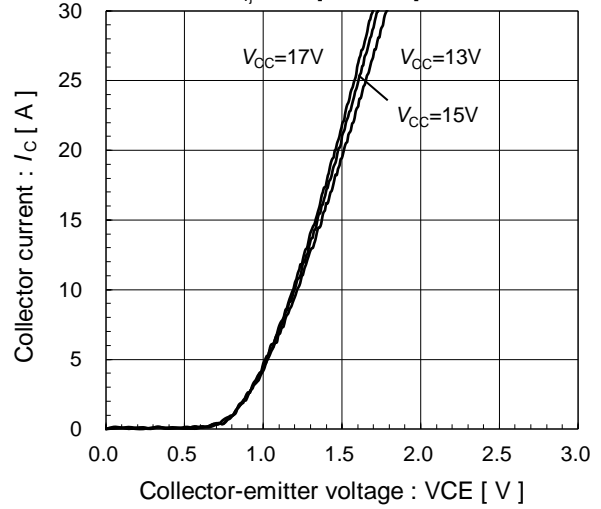
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● Inverter

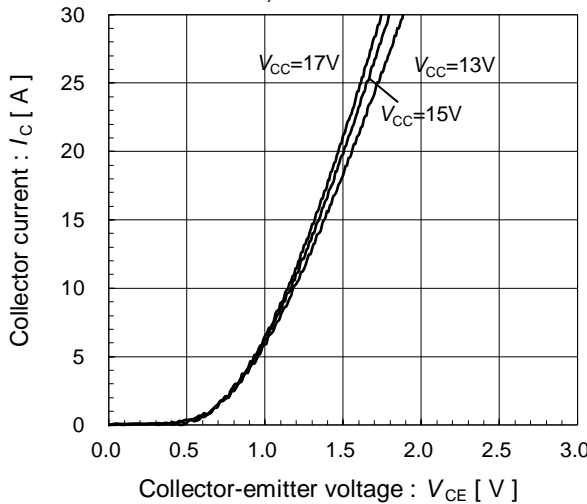
Collector current vs. collector-emitter voltage (typ.)
 $T_{vj}=25^{\circ}\text{C}$ [Chip]



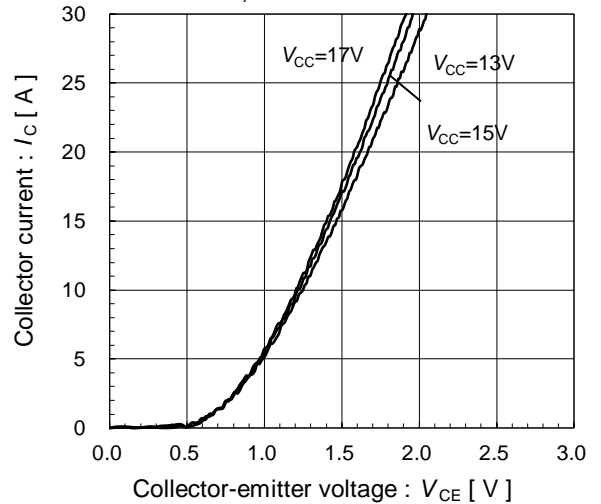
Collector current vs. collector-emitter voltage (typ.)
 $T_{vj}=25^{\circ}\text{C}$ [Terminal]



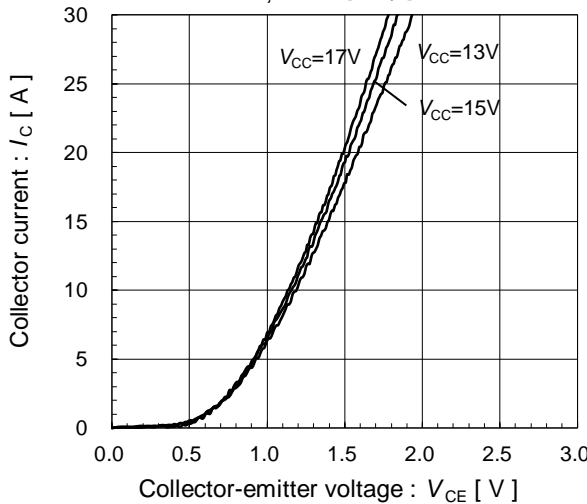
Collector current vs. collector-emitter voltage (typ.)
 $T_{vj}=125^{\circ}\text{C}$ [Chip]



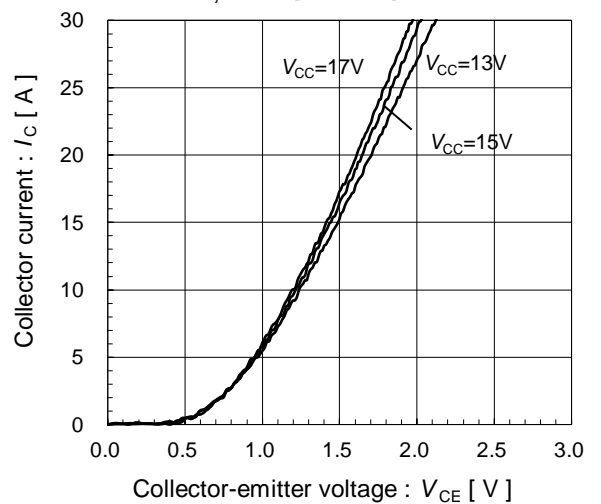
Collector current vs. collector-emitter voltage (typ.)
 $T_{vj}=125^{\circ}\text{C}$ [Terminal]



Collector current vs. collector-emitter voltage (typ.)
 $T_{vj}=150^{\circ}\text{C}$ [Chip]

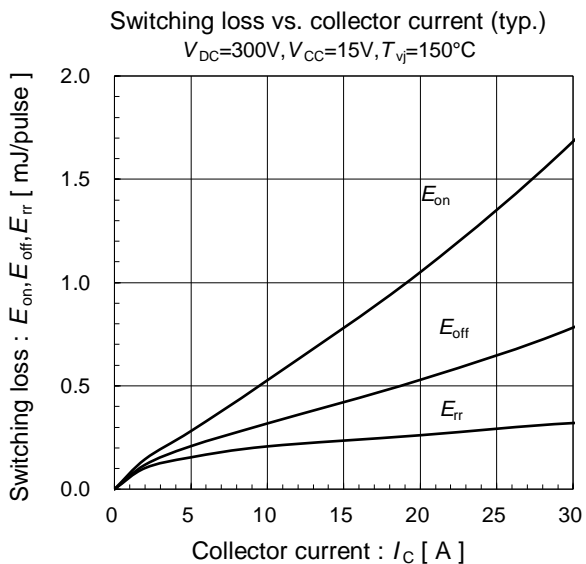
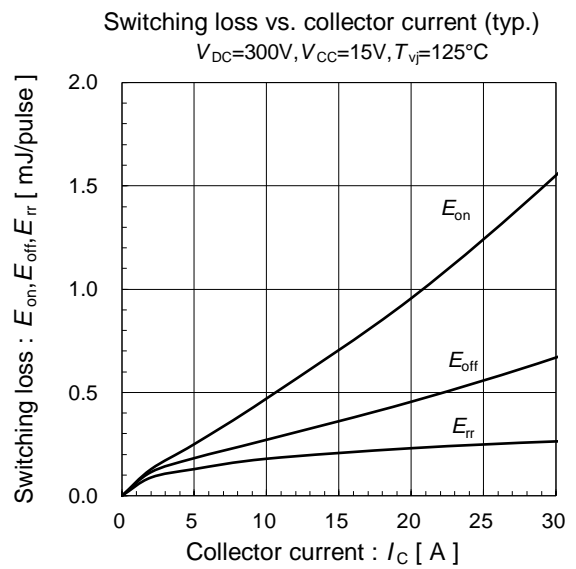
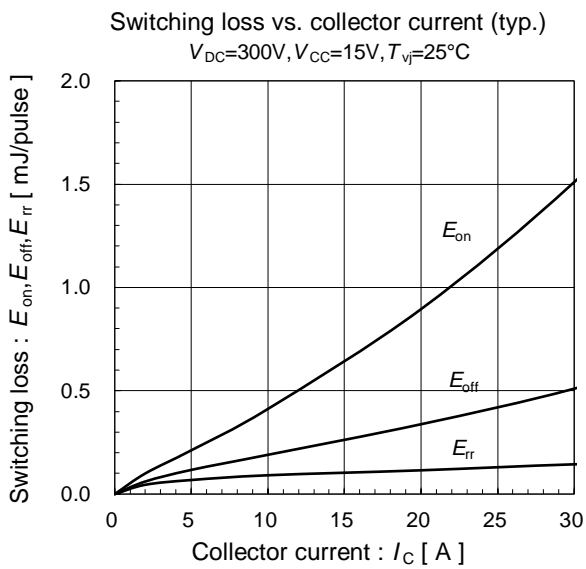
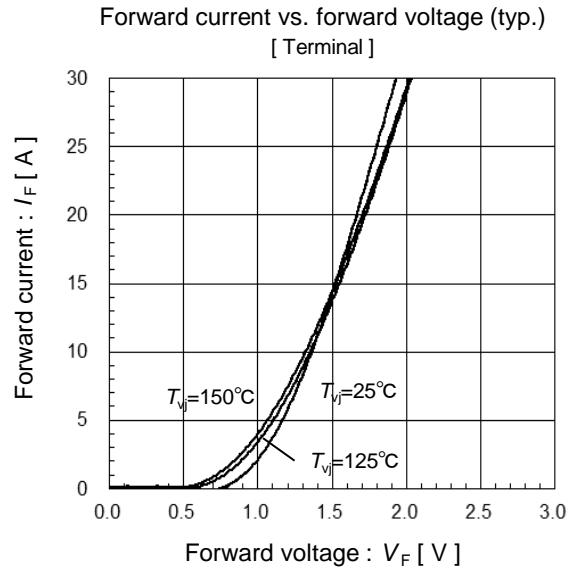
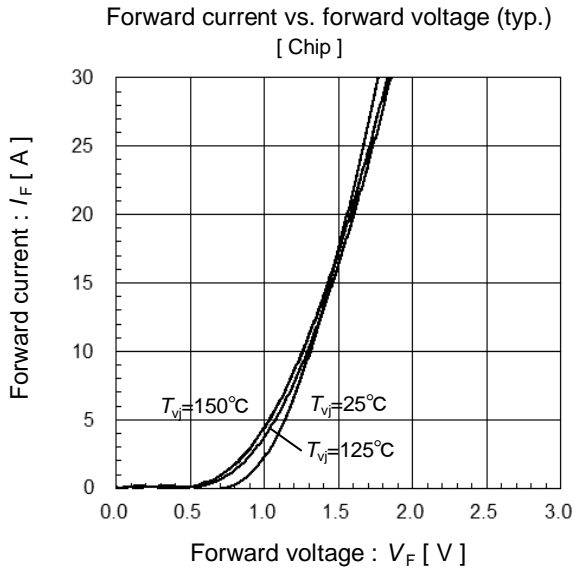


Collector current vs. collector-emitter voltage (typ.)
 $T_{vj}=150^{\circ}\text{C}$ [Terminal]



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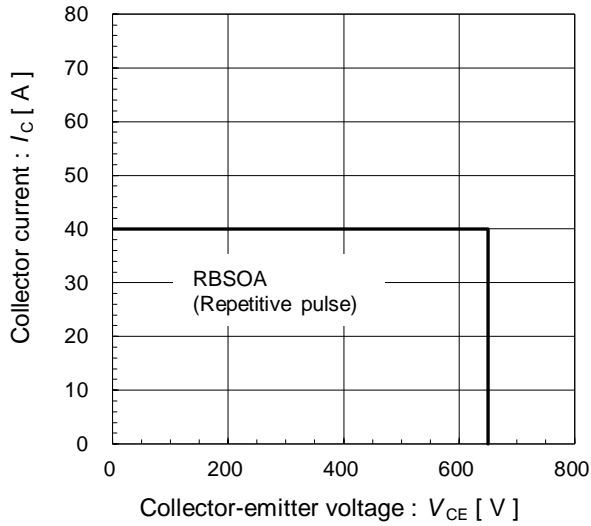
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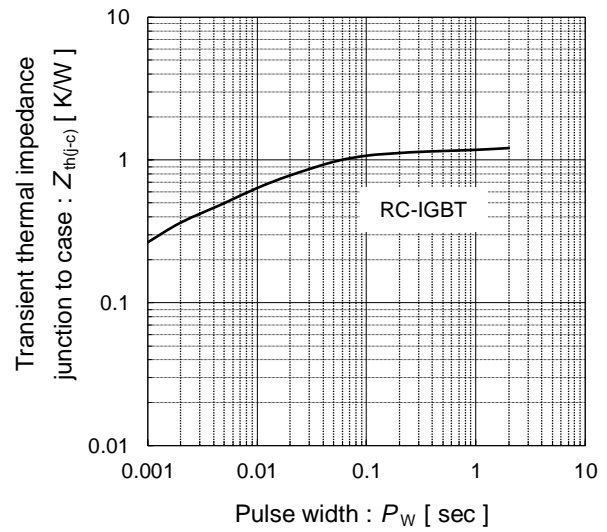
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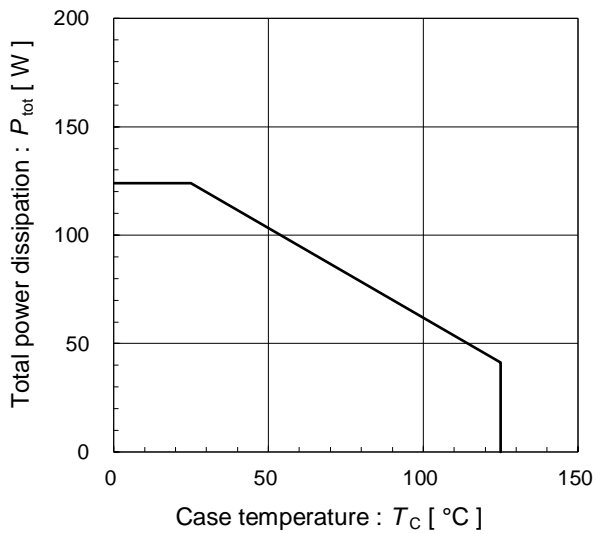
Reversed biased safe operating area (max.)
 $V_{CC}=15V, T_{vj}=150^{\circ}C$



Transient thermal resistance (max.)



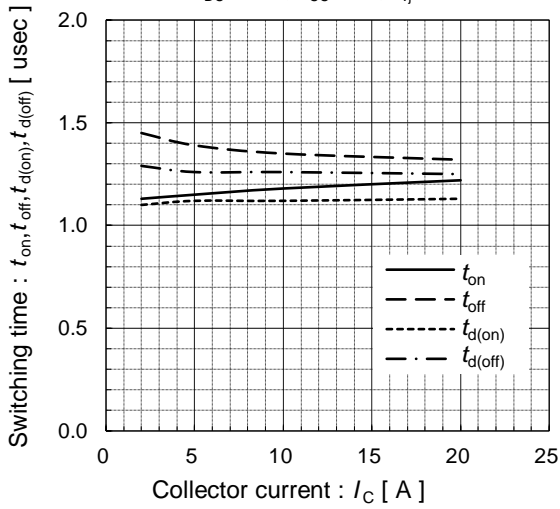
Power derating for RC-IGBT (max.)
 [per device]



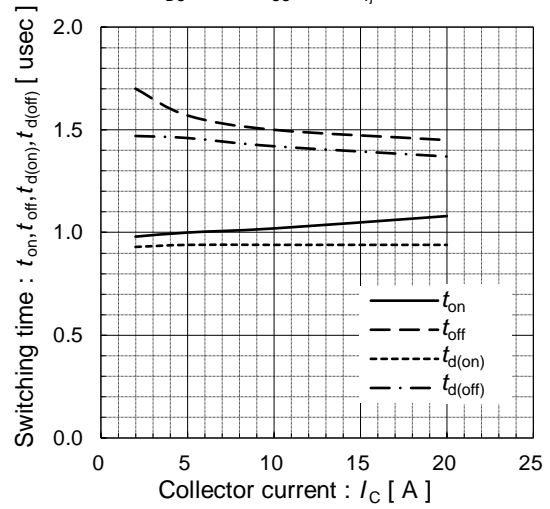
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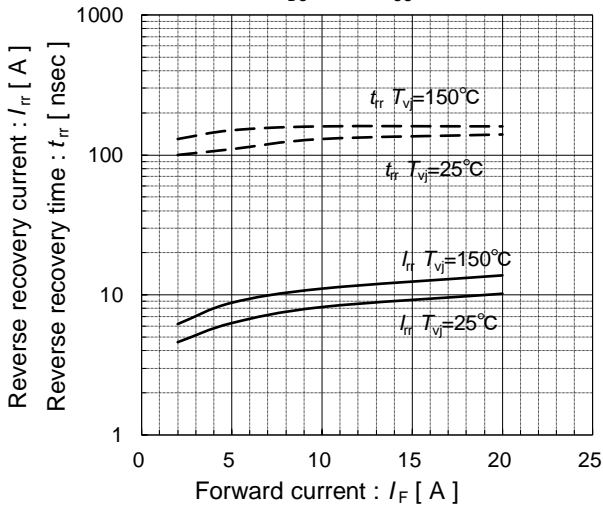
Switching time vs. collector current (typ.)
 $V_{DC}=300V, V_{CC}=15V, T_{vj}=25^{\circ}C$



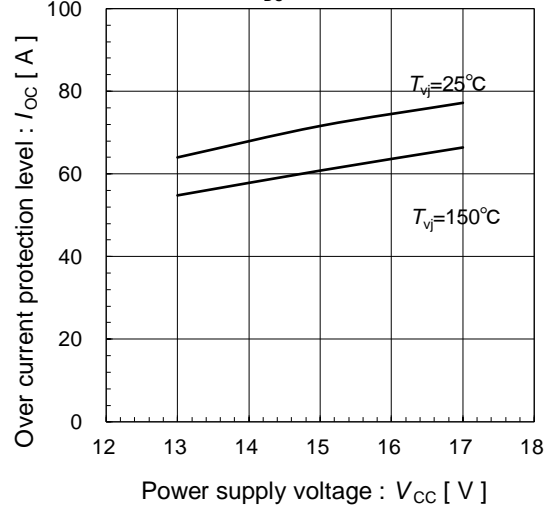
Switching time vs. collector current (typ.)
 $V_{DC}=300V, V_{CC}=15V, T_{vj}=150^{\circ}C$



Reverse recovery characteristics (typ.)
 $V_{DC}=300V, V_{CC}=15V$



Over current protection vs. power supply voltage (typ.)
 $V_{DC}=300V$



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